

ANTREX Electronics

Electronic Components Sourcing Information

Product Reference Information

Part Number: SQJ500AEP-T1_GE3

Manufacturer: Vishay Siliconix

Package: Please confirm with sales

Availability: Please confirm with sales

Product Page:

<https://antrexco.com/product/details/vishay-siliconix/sqj500aep-t1-ge3.html>

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Contact Information

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Quality & Trust

New & Original Components

Supplier verification and packaging condition review

CoC / RoHS / REACH documents available on request

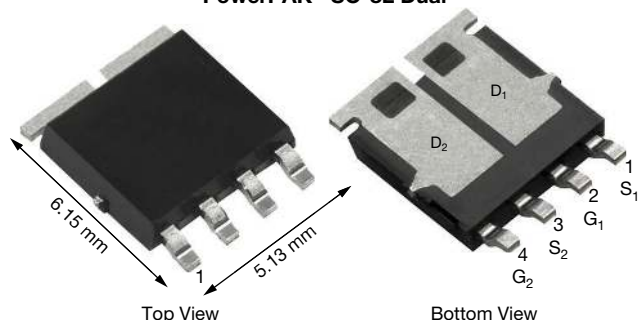
Secure sourcing support for OEM / EMS projects

Note:

This PDF includes an ANTREX product reference cover page.

The original manufacturer datasheet follows from the next page.

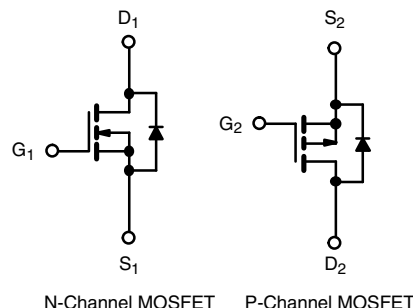
Automotive N- and P-Channel 40 V (D-S) 175 °C MOSFET

PowerPAK® SO-8L Dual


FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified ^d
- 100 % R_g and UIS tested
- Material categorization:
for definitions of compliance please see
www.vishay.com/doc?99912

AUTOMOTIVE
GRADE

RoHS
COMPLIANT
HALOGEN
FREE


PRODUCT SUMMARY

	N-CHANNEL	P-CHANNEL
V _{DS} (V)	40	-40
R _{DS(on)} (Ω) at V _{GS} = ± 10 V	0.0092	0.0270
R _{DS(on)} (Ω) at V _{GS} = ± 4.5 V	0.0112	0.0435
I _D (A)	30	-30
Configuration	N- and p-pair	

ORDERING INFORMATION

Package	PowerPAK SO-8L
Lead (Pb)-free and halogen-free	SQJ500AEP (for detailed order number please see www.vishay.com/doc?79771)

ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)

PARAMETER		SYMBOL	N-CHANNEL	P-CHANNEL	UNIT
Drain-source voltage		V _{DS}	40	-40	V
Gate-source voltage		V _{GS}	± 20		
Continuous drain current ^a	T _C = 25 °C	I _D	30	-30	A
	T _C = 125 °C		30	-18	
Continuous source current (diode conduction) ^a		I _S	30	-30	
Pulsed drain current ^b		I _{DM}	120	-120	
Single pulse avalanche current	L = 0.1 mH	I _{AS}	26.5	-25	
Single pulse avalanche energy		E _{AS}	35	31	mJ
Maximum power dissipation ^b	T _C = 25 °C	P _D	48	48	W
	T _C = 125 °C		16	16	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175		°C
Soldering recommendations (peak temperature) ^{e, f}			260		

THERMAL RESISTANCE RATINGS

PARAMETER	SYMBOL	N-CHANNEL	P-CHANNEL	UNIT
Junction-to-ambient	R _{thJA}	85	85	°C/W
Junction-to-case (drain)	R _{thJC}	3.1	3.1	

Notes

- Package limited
- Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %
- When mounted on 1" square PCB (FR4 material)
- Parametric verification ongoing
- See solder profile (www.vishay.com/doc?73257). The PowerPAK SO-8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- Rework conditions: manual soldering with a soldering iron is not recommended for leadless components



SPECIFICATIONS (T _C = 25 °C, unless otherwise noted)									
PARAMETER		SYMBOL	TEST CONDITIONS			MIN.	TYP.	MAX.	UNIT
Static									
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0 V, I _D = 250 μA		N-Ch	40	-	-	V	
		V _{GS} = 0 V, I _D = -250 μA		P-Ch	-40	-	-		
Gate-source threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA		N-Ch	1.3	1.8	2.3		
		V _{DS} = V _{GS} , I _D = -250 μA		P-Ch	-1.5	-2	-2.5		
Gate-source leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 20 V		N-Ch	-	-	± 100	nA	
				P-Ch	-	-	± 100		
Zero gate voltage drain current	I _{DSS}	V _{GS} = 0 V	V _{DS} = 40 V	N-Ch	-	-	1	μA	
		V _{GS} = 0 V	V _{DS} = -40 V	P-Ch	-	-	-1		
		V _{GS} = 0 V	V _{DS} = 40 V, T _J = 125 °C	N-Ch	-	-	50		
		V _{GS} = 0 V	V _{DS} = -40 V, T _J = 125 °C	P-Ch	-	-	-50		
		V _{GS} = 0 V	V _{DS} = 40 V, T _J = 175 °C	N-Ch	-	-	150		
		V _{GS} = 0 V	V _{DS} = -40 V, T _J = 175 °C	P-Ch	-	-	-150		
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V	V _{DS} ≥ 5 V	N-Ch	25	-	-	A	
		V _{GS} = -10 V	V _{DS} ≤ 5 V	P-Ch	-25	-	-		
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 9.8 A	N-Ch	-	0.0077	0.0092	Ω	
		V _{GS} = -10 V	I _D = -6 A	P-Ch	-	0.0220	0.0270		
		V _{GS} = 10 V	I _D = 9.8 A, T _J = 125 °C	N-Ch	-	-	0.0138		
		V _{GS} = -10 V	I _D = -6 A, T _J = 125 °C	P-Ch	-	-	0.0380		
		V _{GS} = 10 V	I _D = 9.8 A, T _J = 175 °C	N-Ch	-	-	0.0170		
		V _{GS} = -10 V	I _D = -6 A, T _J = 175 °C	P-Ch	-	-	0.0460		
		V _{GS} = 4.5 V	I _D = 8.9 A	N-Ch	-	0.0094	0.0112		
		V _{GS} = -4.5 V	I _D = -4.7 A	P-Ch	-	0.0360	0.0435		
Forward transconductance ^b	g _{fs}	V _{DS} = 15 V, I _D = 9.8 A		N-Ch	-	65	-	S	
		V _{DS} = -15 V, I _D = -6 A		P-Ch	-	16	-		
Dynamic ^b									
Input capacitance	C _{iss}	V _{GS} = 0 V	V _{DS} = 20 V, f = 1 MHz	N-Ch	-	1474	1843	pF	
		V _{GS} = 0 V	V _{DS} = -20 V, f = 1 MHz	P-Ch	-	1302	1628		
Output capacitance	C _{oss}	V _{GS} = 0 V	V _{DS} = 20 V, f = 1 MHz	N-Ch	-	218	273		
		V _{GS} = 0 V	V _{DS} = -20 V, f = 1 MHz	P-Ch	-	222	278		
Reverse transfer capacitance	C _{rss}	V _{GS} = 0 V	V _{DS} = 20 V, f = 1 MHz	N-Ch	-	89	111		
		V _{GS} = 0 V	V _{DS} = -20 V, f = 1 MHz	P-Ch	-	154	193		
Total gate charge ^c	Q _g	V _{GS} = 10 V	V _{DS} = 20 V, I _D = 10 A	N-Ch	-	25.5	38.3	nC	
		V _{GS} = -10 V	V _{DS} = -20 V, I _D = -10 A	P-Ch	-	30.2	45		
Gate-source charge ^c	Q _{gs}	V _{GS} = 10 V	V _{DS} = 20 V, I _D = 10 A	N-Ch	-	4.4	-		
		V _{GS} = -10 V	V _{DS} = -20 V, I _D = -10 A	P-Ch	-	4.1	-		
Gate-drain charge ^c	Q _{gd}	V _{GS} = 10 V	V _{DS} = 20 V, I _D = 10 A	N-Ch	-	4.3	-		
		V _{GS} = -10 V	V _{DS} = -20 V, I _D = -10 A	P-Ch	-	7.4	-		
Gate resistance	R _g	f = 1 MHz		N-Ch	0.65	1.37	2.1	Ω	
				P-Ch	3.1	6.15	9.5		

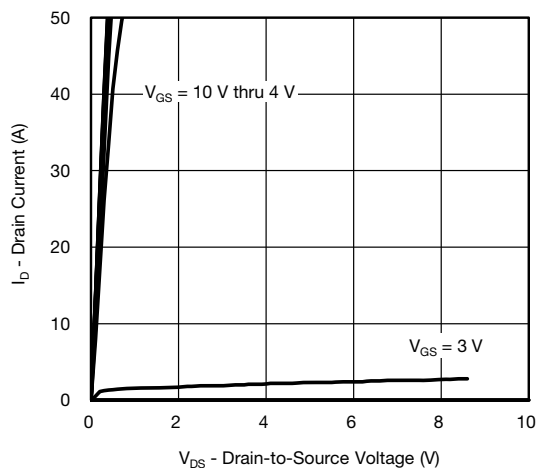
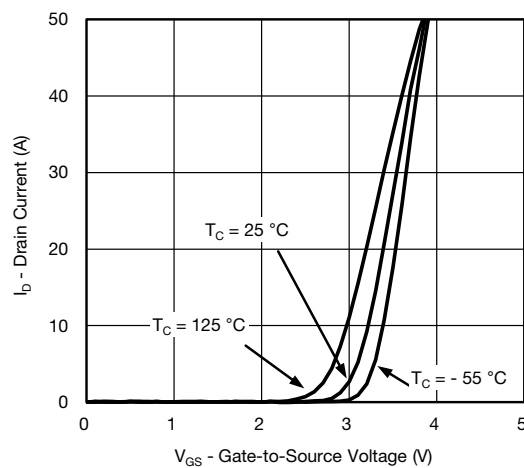
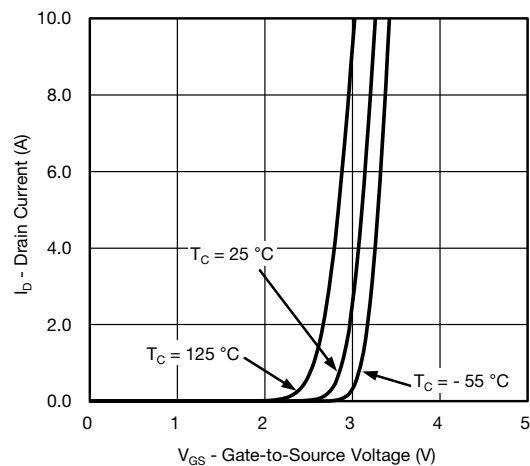
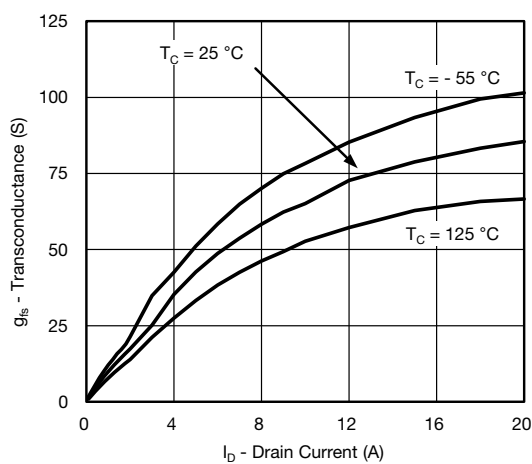
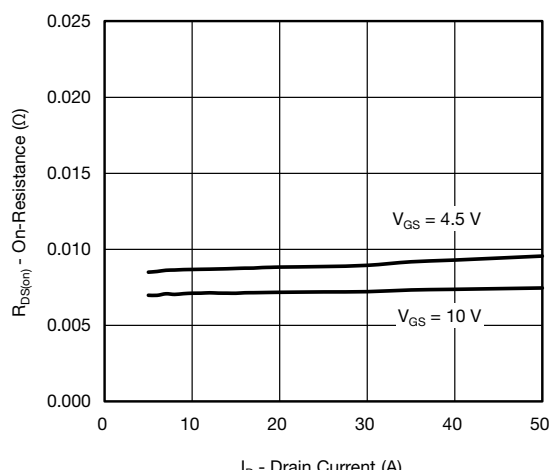
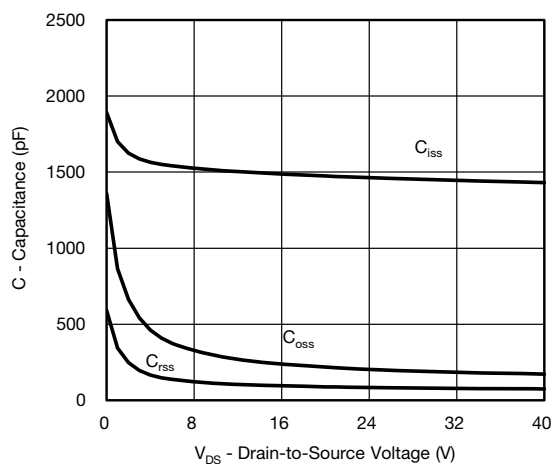


SPECIFICATIONS (T _C = 25 °C, unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Dynamic ^b							
Turn-on delay time ^c	t _{d(on)}	V _{DD} = 20 V, R _L = 2 Ω I _D ≅ 10 A, V _{GEN} = 10 V, R _g = 1 Ω	N-Ch	-	8	12	ns
		V _{DD} = -20 V, R _L = 2 Ω I _D ≅ -10 A, V _{GEN} = -10 V, R _g = 1 Ω	P-Ch	-	7	11	
Rise time ^c	t _r	V _{DD} = 20 V, R _L = 2 Ω I _D ≅ 10 A, V _{GEN} = 10 V, R _g = 1 Ω	N-Ch	-	12	18	
		V _{DD} = -20 V, R _L = 2 Ω I _D ≅ -10 A, V _{GEN} = -10 V, R _g = 1 Ω	P-Ch	-	9	13	
Turn-off delay time ^c	t _{d(off)}	V _{DD} = 20 V, R _L = 2 Ω I _D ≅ 10 A, V _{GEN} = 10 V, R _g = 1 Ω	N-Ch	-	22	33	
		V _{DD} = -20 V, R _L = 2 Ω I _D ≅ -10 A, V _{GEN} = -10 V, R _g = 1 Ω	P-Ch	-	43	64	
Fall time ^c	t _f	V _{DD} = 20 V, R _L = 2 Ω I _D ≅ 10 A, V _{GEN} = 10 V, R _g = 1 Ω	N-Ch	-	10	16	
		V _{DD} = -20 V, R _L = 2 Ω I _D ≅ -10 A, V _{GEN} = -10 V, R _g = 1 Ω	P-Ch	-	19	28	
Source-Drain Diode Ratings and Characteristics ^b							
Pulsed current ^a	I _{SM}		N-Ch	-	-	120	A
			P-Ch	-	-	-120	
Forward voltage	V _{SD}	I _S = 6.5 A	N-Ch	-	0.79	1.2	V
		I _S = -3.4 A	P-Ch	-	-0.78	-1.2	

Notes

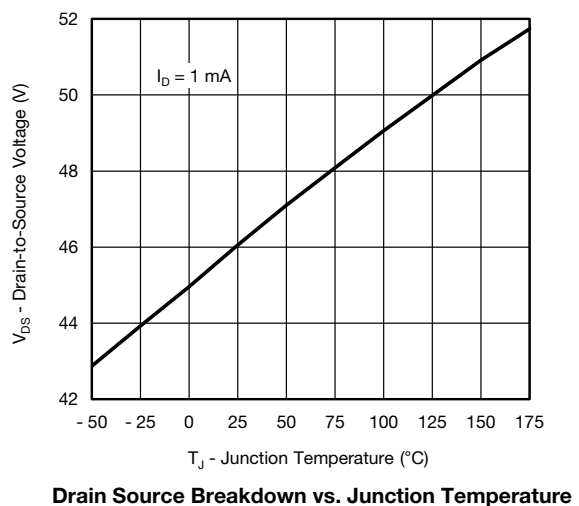
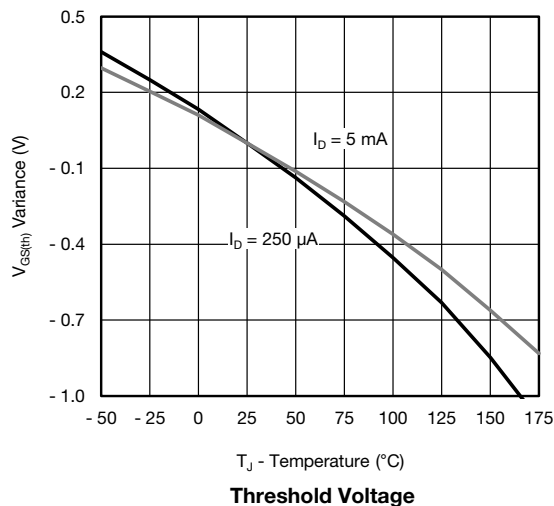
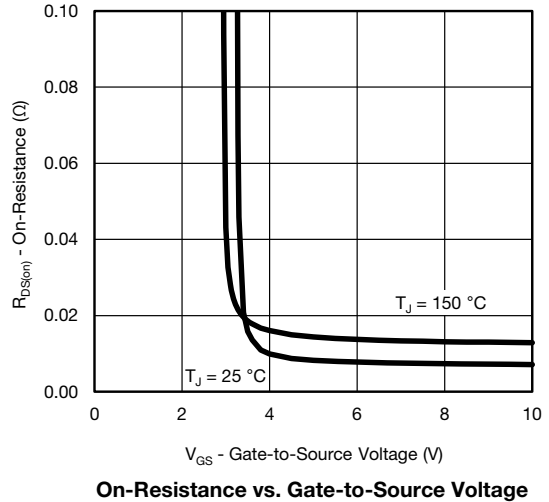
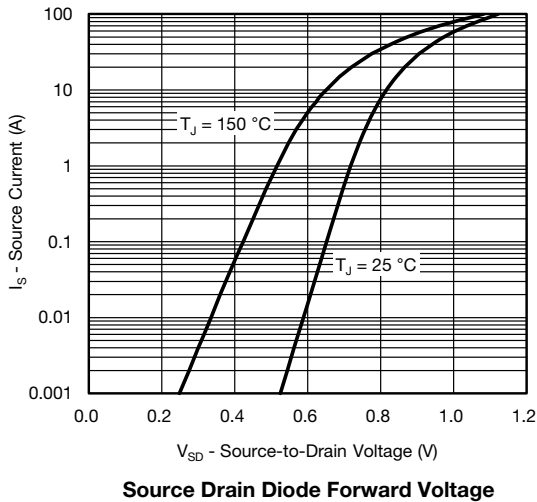
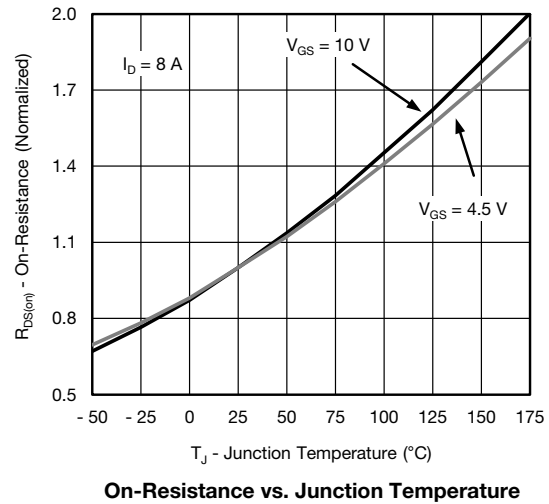
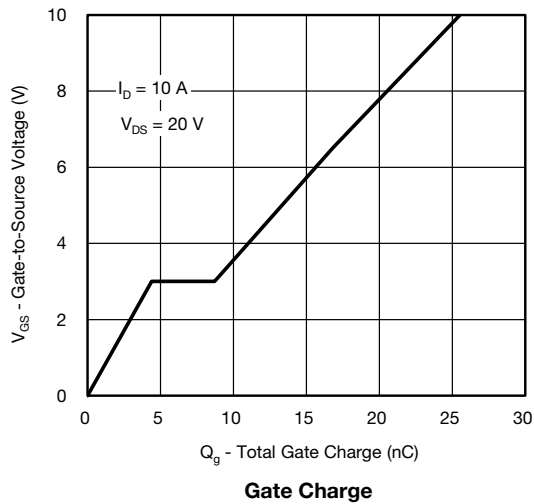
- g. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$
h. Guaranteed by design, not subject to production testing
i. Independent of operating temperature

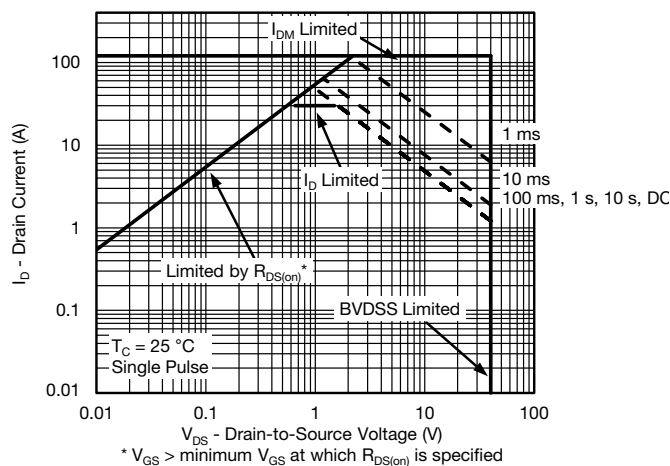
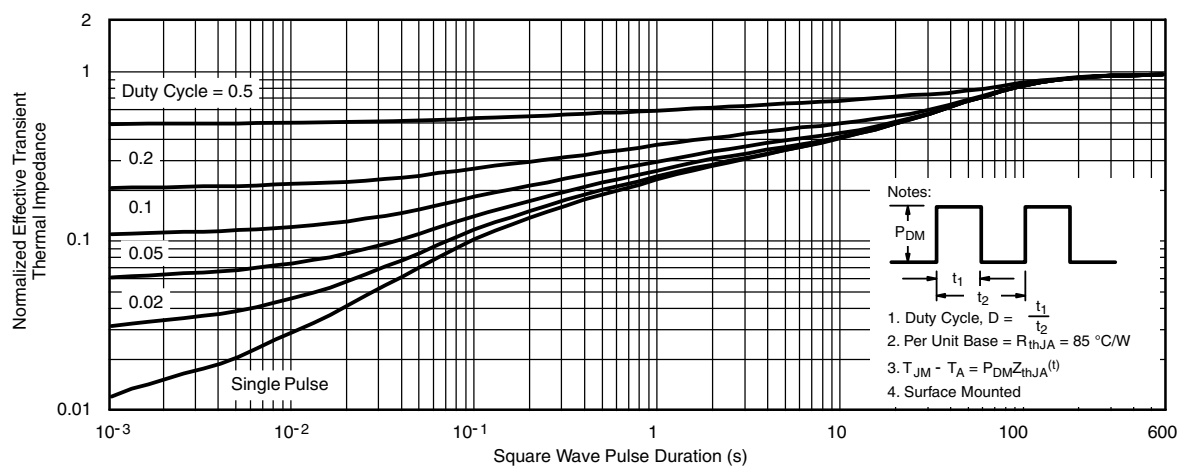
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

N-CHANNEL TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

Output Characteristics

Transfer Characteristics

Transfer Characteristics

Transconductance

On-Resistance vs. Drain Current

Capacitance



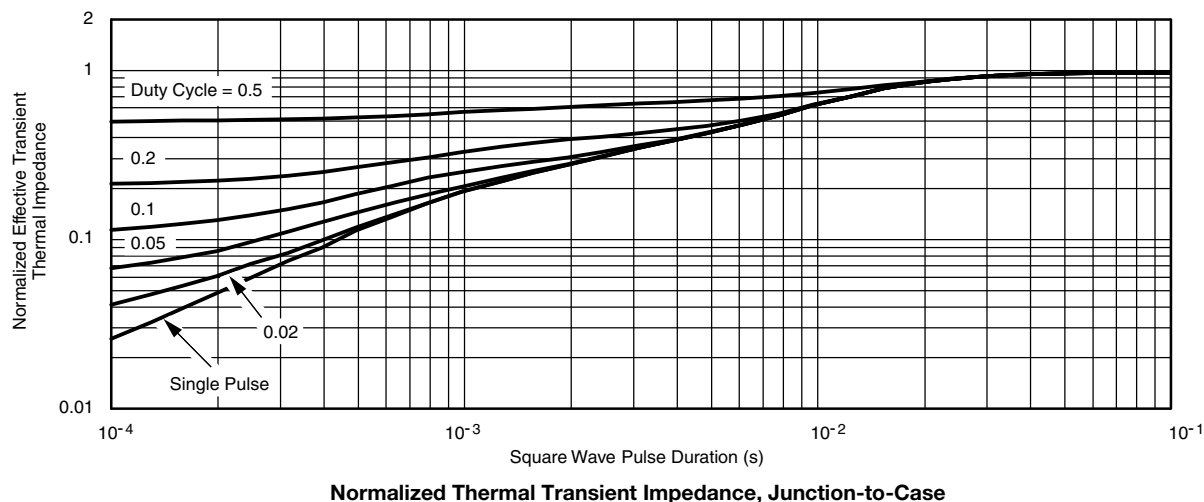
N-CHANNEL TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)



N-CHANNEL TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)

Safe Operating Area

Normalized Thermal Transient Impedance, Junction-to-Ambient



N-CHANNEL TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)

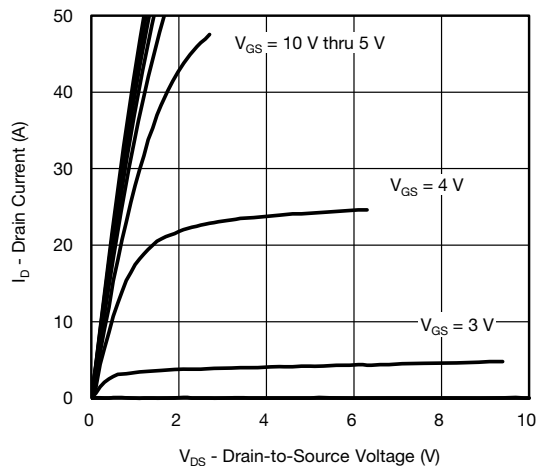


Note

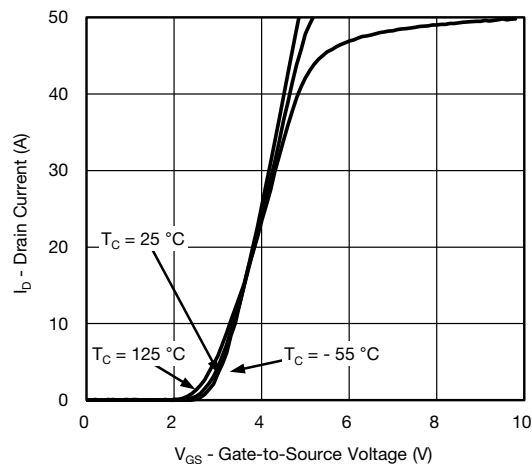
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient ($25\text{ }^{\circ}\text{C}$)
 - Normalized Transient Thermal Impedance Junction-to-Case ($25\text{ }^{\circ}\text{C}$)are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions



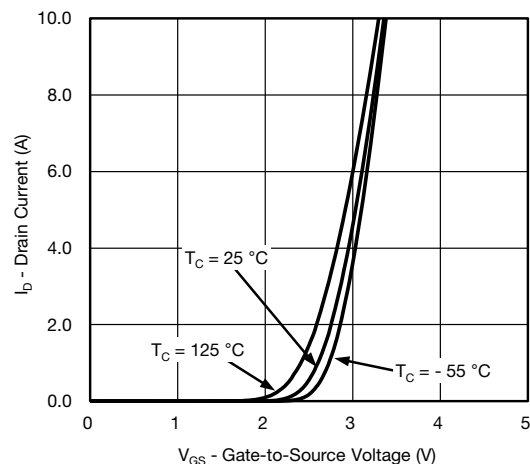
P-CHANNEL TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)



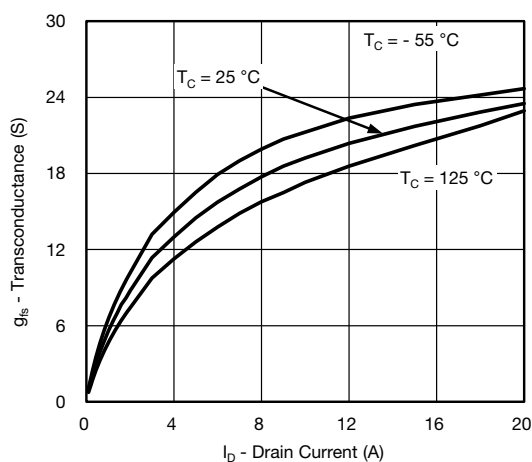
Output Characteristics



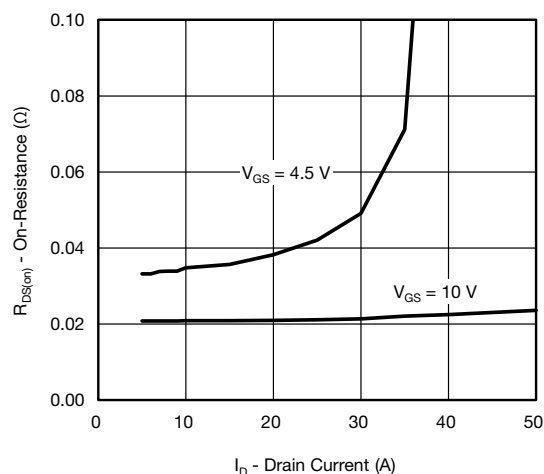
Transfer Characteristics



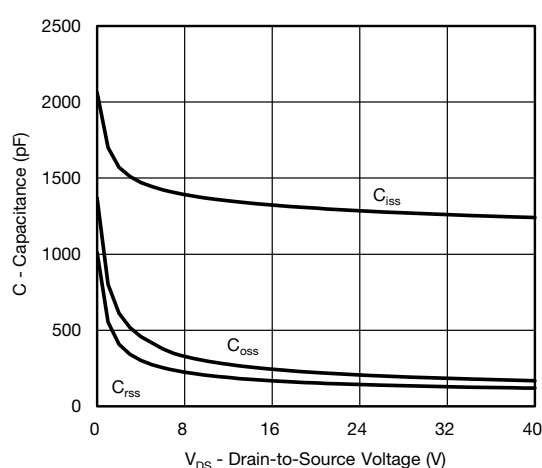
Transfer Characteristics



Transconductance



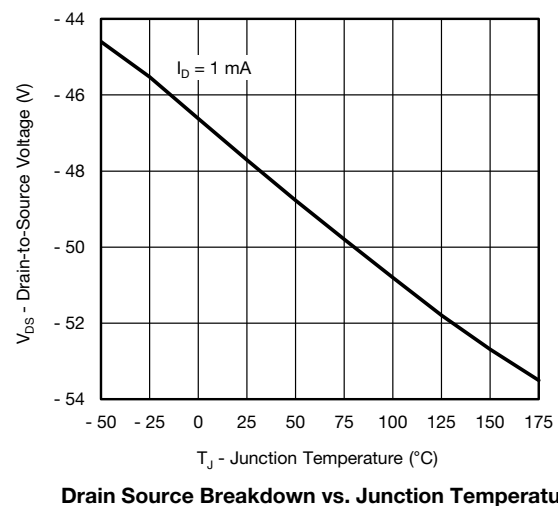
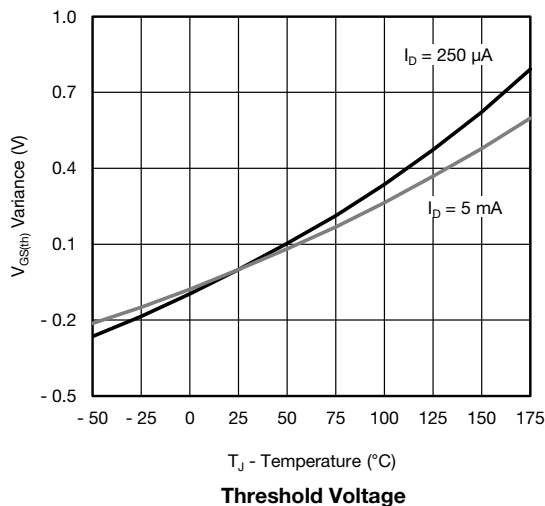
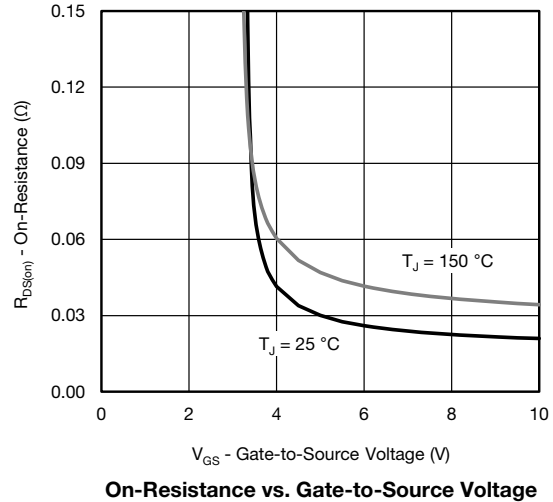
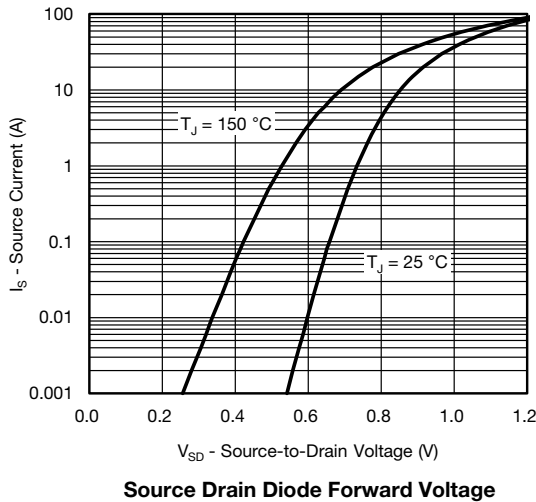
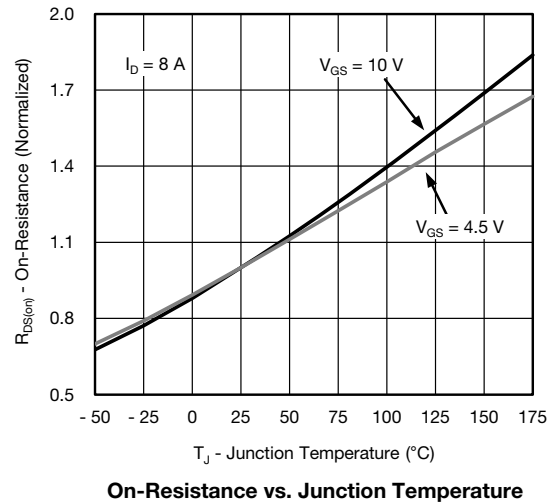
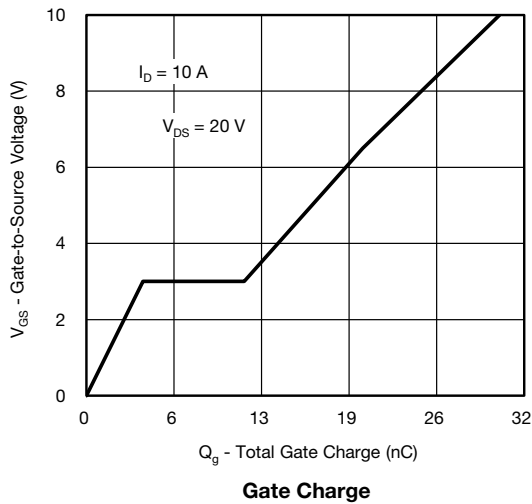
On-Resistance vs. Drain Current

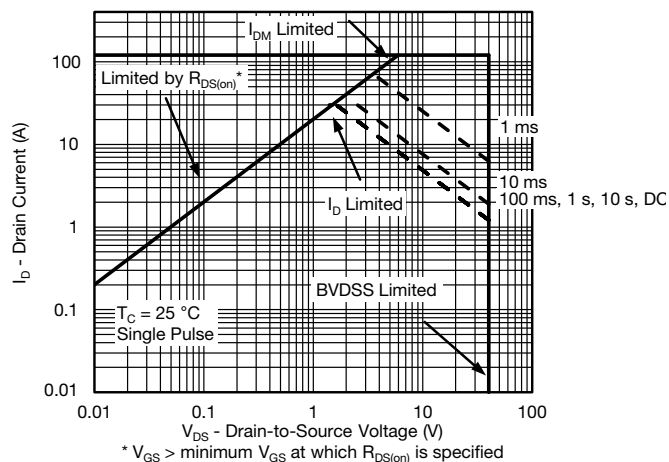
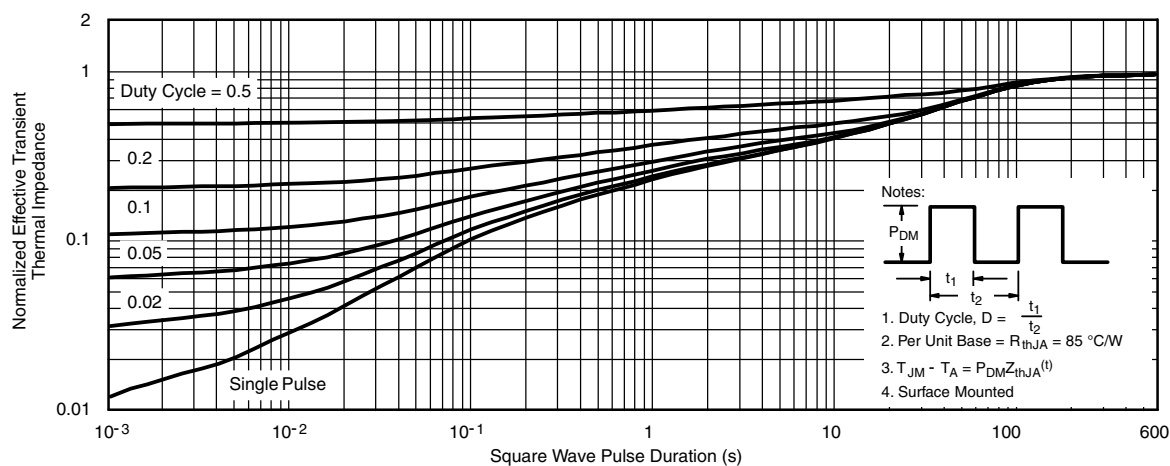


Capacitance



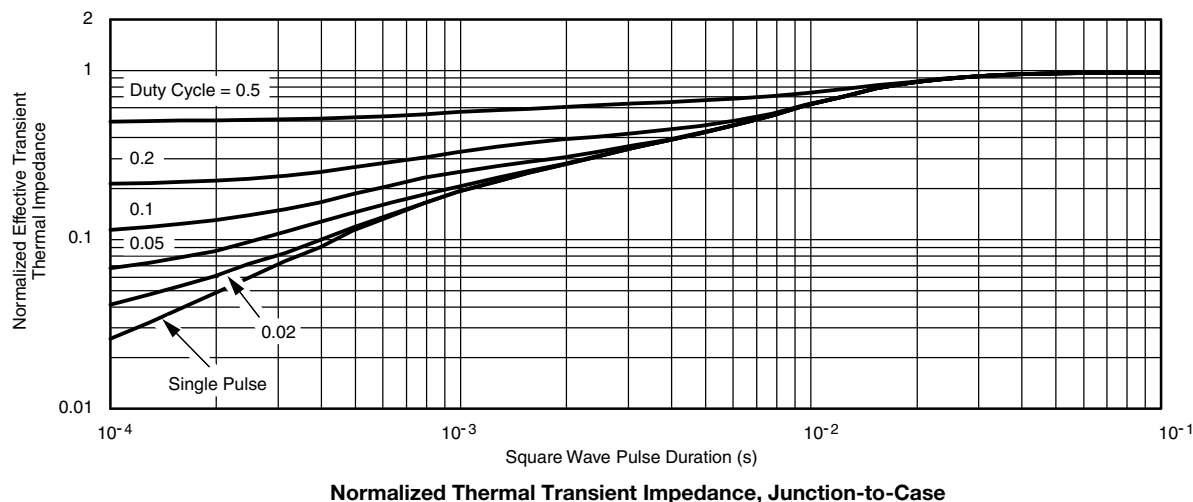
P-CHANNEL TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)



P-CHANNEL TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)

Safe Operating Area

Normalized Thermal Transient Impedance, Junction-to-Ambient



P-CHANNEL TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)



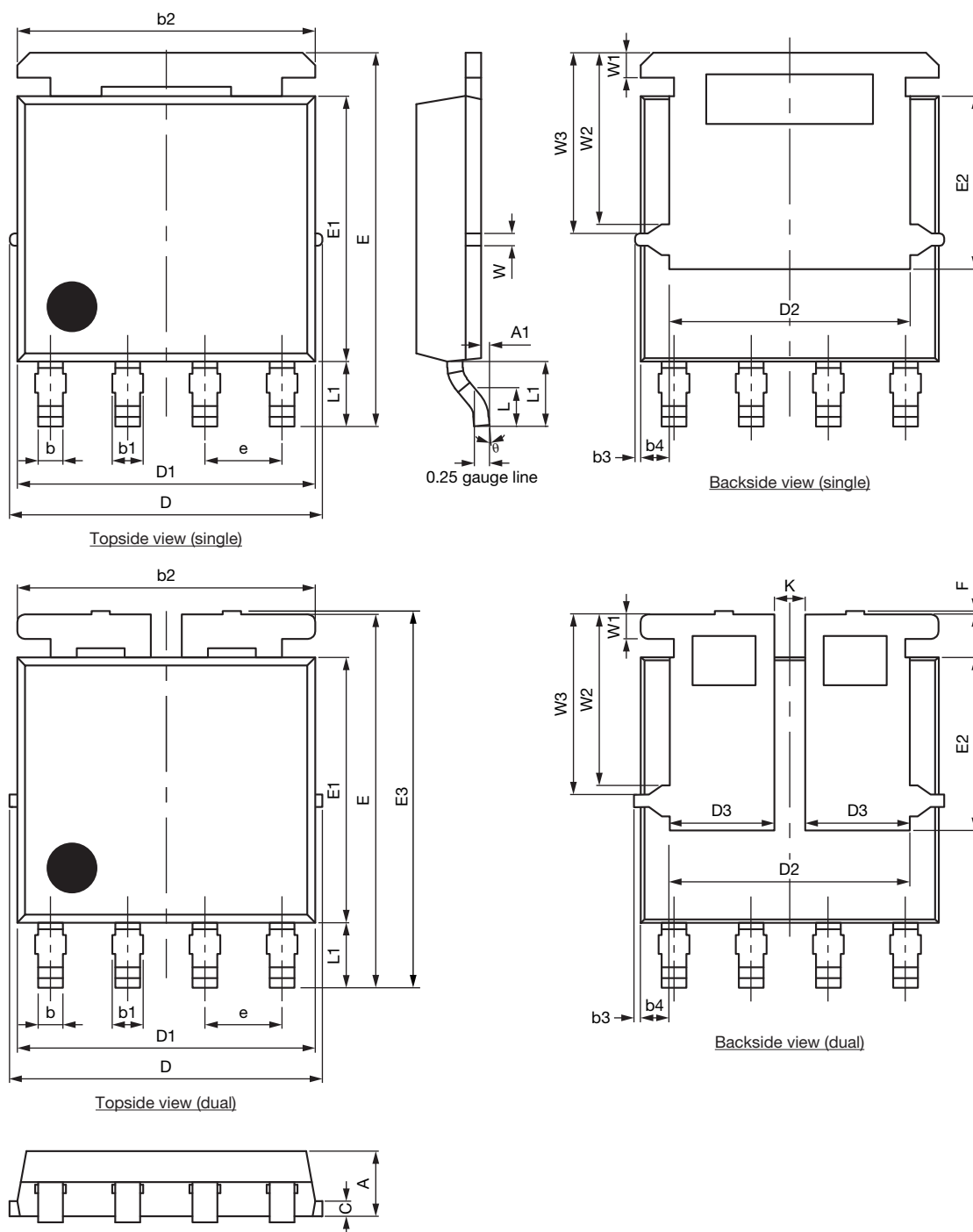
Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient ($25\text{ }^{\circ}\text{C}$)
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Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?62878.



PowerPAK® SO-8L Case Outline 2





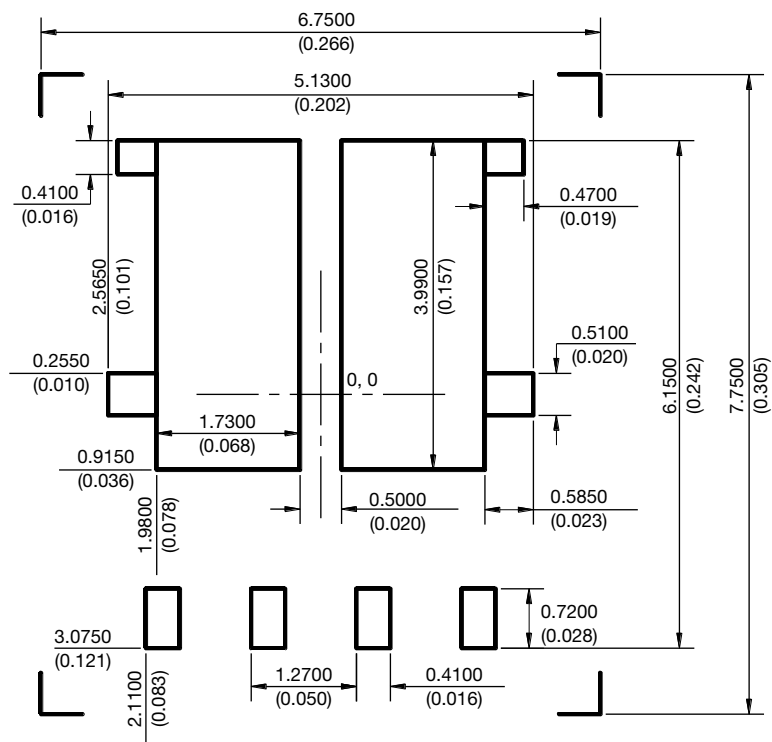
DIM.	MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	1.00	1.07	1.14	0.039	0.042	0.045
A1	0.00	-	0.127	0.00	-	0.005
b	0.33	0.41	0.48	0.013	0.016	0.019
b1	0.44	0.51	0.58	0.017	0.020	0.023
b2	4.80	4.90	5.00	0.189	0.193	0.197
b3	0.094			0.004		
b4	0.47			0.019		
c	0.20	0.25	0.30	0.008	0.010	0.012
D	5.00	5.13	5.25	0.197	0.202	0.207
D1	4.80	4.90	5.00	0.189	0.193	0.197
D2	3.86	3.96	4.06	0.152	0.156	0.160
D3	1.63	1.73	1.83	0.064	0.068	0.072
e	1.27 BSC			0.050 BSC		
E	6.05	6.15	6.25	0.238	0.242	0.246
E1	4.27	4.37	4.47	0.168	0.172	0.176
E2	2.75	2.85	2.95	0.108	0.112	0.116
E3	6.05	6.22	6.40	0.238	0.245	0.252
F	-	-	0.15	-	-	0.006
L	0.62	0.72	0.82	0.024	0.028	0.032
L1	0.92	1.07	1.22	0.036	0.042	0.048
K	0.51			0.020		
W	0.23			0.009		
W1	0.41			0.016		
W2	2.82			0.111		
W3	2.96			0.117		
θ	0°	-	10°	0°	-	10°
ECN: C23-1026-Rev. D, 25-Sep-2023 DWG: 6044						

Note

- Millimeters will govern



RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L DUAL



Recommended Minimum Pads
Dimensions in mm (inches)
Keep-out 6.75 (0.266) x 7.75 (0.305)



Disclaimer

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